#### Advance Information

# Low-Voltage CMOS Octal Latching Transceiver

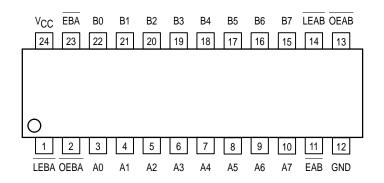
# With 5V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX543 is a high performance, non–inverting octal latching transceiver operating from a 2.7 to 3.6V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A V<sub>I</sub> specification of 5.5V allows MC74LCX543 inputs to be safely driven from 5V devices. The MC74LCX543 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

For data flow from A to B with the EAB LOW, the A-to-B Output Enable (OEAB) must be LOW in order to enable data to the B bus, as indicated in the Function Table. With EAB LOW, a LOW signal on the A-to-B Latch Enable (LEAB) input makes the A-to-B latches transparent; a subsequent LOW-to-HIGH transition of the LEAB signal will latch the A latches, and the outputs no longer change with the A inputs. With EAB and OEAB both LOW, the 3-State B output buffers are active and reflect the data present at the output of the A latches. Control of data flow from B to A is symetric to that above, but uses the EBA, LEBA, and OEBA inputs.

- Designed for 2.7 to 3.6V VCC Operation
- 5V Tolerant Interface Capability With 5V TTL Logic
- Supports Live Insertion and Withdrawal
- I<sub>OFF</sub> Specification Guarantees High Impedance When V<sub>CC</sub> = 0V
- LVTTL Compatible
- LVCMOS Compatible
- 24mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10μA) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V; Machine Model >200V

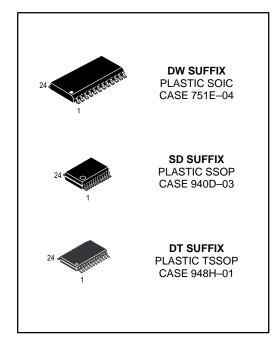
#### Pinout: 24-Lead Package (Top View)



## **MC74LCX543**



### LOW-VOLTAGE CMOS OCTAL LATCHING TRANSCEIVER



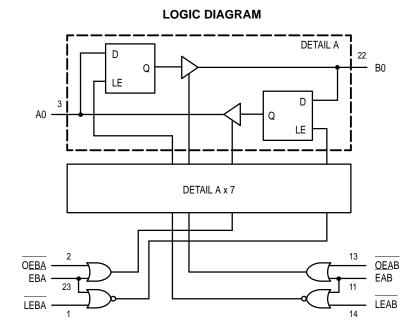
#### **PIN NAMES**

Pins	Function
OExx Exx LExx A0-A7 B0-B7	Output Enable Inputs Enable Inputs Latch Enable Inputs 3-State Inputs/Outputs 3-State Inputs/Outputs

This document contains information on a new product. Specifications and information herein are subject to change without notice.

11/96





#### **FUNCTION TABLE**

		ln	puts			Da Po	nta rts	Operating Mode
OEAB	OEBA	EAB	EBA	LEAB	LEBA	An	Bn	
Н	Н					Input	Input	
		Х	Х	Х	Х	Х	Х	Disable Outputs
		L	L	L	L	Х	Х	Transparent Data; Outputs Disabled
				Н	Н	l h	l h	Latch and Outputs Disabled
L	Н					Input	Output	
		Н	X*	L	Х	l h	Z Z	Load and B Outputs Disabled
				Н	Х	Х	Z	Hold; B Outputs Disabled
		L	X*	L	Х	L H	L H	Transparent A to B
				Н	Х	l h	L H	Latch and Display B Outputs
Н	L					Output	Input	
		X*	Н	Х	L	Z Z	l h	Load and A Outputs Disabled
				Х	Н	Z	Х	Hold; A Outputs DIsabled
		X*	L	Х	L	L H	L H	Transparent B to A
				Х	Н	L H	l h	Latch and Display A Outputs

 $H = High\ Voltage\ Level;\ h = High\ Voltage\ Level\ One\ Setup\ Time\ Prior\ to\ the\ Latch\ Enable\ or\ Enable\ Low-to-High\ Transition;\ L = Low\ Voltage\ Level;\ l = Low\ Voltage\ Level\ One\ Setup\ Time\ Prior\ to\ the\ Latch\ Enable\ or\ Enable\ Low-to-High\ Transition;\ X = Don't\ Care;\ ^* = The\ latch\ es\ are\ not\ internally\ gated\ with\ the\ Output\ Enables.$  Therefore, data at the A or B ports may enter the latches at any time, provided that the\ LExx\ and\ Exx\ pins\ are\ set\ accordingly. For\ I\_{CC}\ reasons,\ Do\ Not\ Float\ Inputs.

#### **ABSOLUTE MAXIMUM RATINGS\***

Symbol	Parameter	Value	Condition	Unit
Vcc	DC Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 ≤ V <sub>I</sub> ≤ +7.0		V
Vo	DC Output Voltage	$-0.5 \le V_{O} \le +7.0$	Output in 3–State	V
		$-0.5 \le V_{O} \le V_{CC} + 0.5$	Note 1.	V
ΙΙΚ	DC Input Diode Current	-50	V <sub>I</sub> < GND	mA
loк	DC Output Diode Current	-50	V <sub>O</sub> < GND	mA
		+50	AO > ACC	mA
IO	DC Output Source/Sink Current	±50		mA
ICC	DC Supply Current Per Supply Pin	±100		mA
IGND	DC Ground Current Per Ground Pin	±100		mA
T <sub>STG</sub>	Storage Temperature Range	-65 to +150		°C

<sup>\*</sup> Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute—maximum—rated conditions is not implied.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Тур	Max	Unit
Vcc	Supply Voltage Operating Data Retention Only	2.0 1.5	3.3 3.3	3.6 3.6	V
VI	Input Voltage	0		5.5	V
Vo	Output Voltage (HIGH or LOW State) (3–State)	0 0		V <sub>CC</sub> 5.5	V
IOH	HIGH Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			-24	mA
loL	LOW Level Output Current, V <sub>CC</sub> = 3.0V – 3.6V			24	mA
<sup>I</sup> ОН	HIGH Level Output Current, V <sub>CC</sub> = 2.7V – 3.0V			-12	mA
loL	LOW Level Output Current, V <sub>CC</sub> = 2.7V – 3.0V			12	mA
T <sub>A</sub>	Operating Free–Air Temperature	-40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, $V_{IN}$ from 0.8V to 2.0V, $V_{CC}$ = 3.0V	0		10	ns/V

#### DC ELECTRICAL CHARACTERISTICS

			T <sub>A</sub> = -40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
VIH	HIGH Level Input Voltage (Note 2.)	2.7V ≤ V <sub>CC</sub> ≤ 3.6V	2.0		V
VIL	LOW Level Input Voltage (Note 2.)	2.7V ≤ V <sub>CC</sub> ≤ 3.6V		0.8	V
VOH	HIGH Level Output Voltage	$2.7V \le V_{CC} \le 3.6V$ ; $I_{OH} = -100\mu A$	V <sub>CC</sub> - 0.2		V
		$V_{CC} = 2.7V; I_{OH} = -12mA$	2.2		
		$V_{CC} = 3.0V; I_{OH} = -18mA$	2.4		
		$V_{CC} = 3.0V; I_{OH} = -24mA$	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	$2.7V \le V_{CC} \le 3.6V; I_{OL} = 100\mu A$		0.2	V
		$V_{CC} = 2.7V; I_{OL} = 12mA$		0.4	
		V <sub>CC</sub> = 3.0V; I <sub>OL</sub> = 16mA		0.4	
		$V_{CC} = 3.0V; I_{OL} = 24mA$		0.55	

<sup>2.</sup> These values of  $V_{\parallel}$  are used to test DC electrical characteristics only.

<sup>1.</sup> Output in HIGH or LOW State. I<sub>O</sub> absolute maximum rating must be observed.

#### DC ELECTRICAL CHARACTERISTICS (continued)

			T <sub>A</sub> = -40°C to +85°C		
Symbol	Characteristic	Condition	Min	Max	Unit
Ц	Input Leakage Current	$2.7V \le V_{CC} \le 3.6V; \ 0V \le V_{I} \le 5.5V$		±5.0	μΑ
loz	3–State Output Current	$2.7 \le V_{CC} \le 3.6V$ ; $0V \le V_{O} \le 5.5V$ ; $V_{I} = V_{IH}$ or $V_{IL}$		±5.0	μΑ
lOFF	Power-Off Leakage Current	$V_{CC} = 0V; V_{I} \text{ or } V_{O} = 5.5V$		10	μΑ
ICC	Quiescent Supply Current	$2.7 \le V_{CC} \le 3.6V$ ; $V_I = GND$ or $V_{CC}$		10	μΑ
		$2.7 \le V_{CC} \le 3.6V$ ; $3.6 \le V_I$ or $V_O \le 5.5V$		±10	μΑ
Δlcc	Increase in I <sub>CC</sub> per Input	$2.7 \le V_{CC} \le 3.6V; V_{IH} = V_{CC} - 0.6V$		500	μΑ

### AC CHARACTERISTICS (Note 3.; $t_R = t_F = 2.5$ ns; $C_L = 50$ pF; $R_L = 500\Omega$ )

			Limits				
			T <sub>A</sub> = -40°C to +85°C				1 l
			V <sub>CC</sub> = 3.	0V to 3.6V	VCC	= 2.7V	1
Symbol	Parameter	Waveform	Min	Max	Min	Max	Unit
<sup>t</sup> PLH <sup>t</sup> PHL	Propagation Delay An to Bn or Bn to An	1	1.5 1.5	7.0 7.0	1.5 1.5	8.0 8.0	ns
<sup>t</sup> PLH <sup>t</sup> PHL	<u>Propag</u> ation D <u>elay</u> LEBA to An or LEAB to Bn	4	1.5 1.5	8.5 8.5	1.5 1.5	9.5 9.5	ns
<sup>t</sup> PZH <sup>t</sup> PZL	Output Enable Time OEBA to An or OEAB to Bn	2	1.5 1.5	9.0 9.0	1.5 1.5	10.0 10.0	ns
<sup>t</sup> PHZ <sup>t</sup> PLZ	Output Disable Time OEBA to An or OEAB to Bn	2	1.5 1.5	7.0 7.0	1.5 1.5	7.5 7.5	ns
<sup>t</sup> PZH <sup>t</sup> PZL	Output Enable Time EBA to An or EAB to Bn	2	1.5 1.5	9.0 9.0	1.5 1.5	10.0 10.0	ns
<sup>t</sup> PHZ <sup>t</sup> PLZ	Output Disabl <u>e Time</u> EBA to An or EAB to Bn	2	1.5 1.5	7.0 7.0	1.5 1.5	7.5 7.5	ns
t <sub>S</sub>	Setup Time, HIGH to LOW Data to LExx	4	2.5		2.5		ns
th	Hold Time, HIGH to LOW Data to LExx	4	1.5		1.5		ns
t <sub>S</sub>	Setup Time, HIGH to LOW Data to Exx	4	2.5		2.5		ns
th	Hold Time, HIGH to LOW Data to Exx	4	1.5		1.5		ns
t <sub>W</sub>	Latch Enable or Enable Pulse Width, LOW	4	3.3		3.3		ns
tOSHL tOSLH	Output-to-Output Skew (Note 4.)		The section	1.0		A-11	ns

<sup>3.</sup> These AC parameters are preliminary and may be modified prior to release. The maximum AC limits are design targets. Actual performance will be specified upon completion of characterization.

#### **DYNAMIC SWITCHING CHARACTERISTICS**

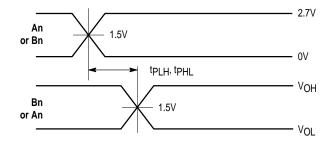
			T <sub>A</sub> = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
VOLP	Dynamic LOW Peak Voltage (Note 5.)	$V_{CC} = 3.3V$ , $C_L = 50pF$ , $V_{IH} = 3.3V$ , $V_{IL} = 0V$		0.8		V
VOLV	Dynamic LOW Valley Voltage (Note 5.)	$V_{CC} = 3.3V$ , $C_L = 50pF$ , $V_{IH} = 3.3V$ , $V_{IL} = 0V$		0.8		V

<sup>5.</sup> Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

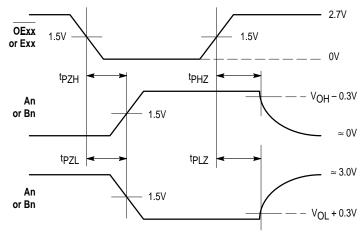
<sup>4.</sup> Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>); parameter guaranteed by design.

#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Parameter Condition		Unit
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	7	pF
C <sub>I/O</sub>	Input/Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	25	pF

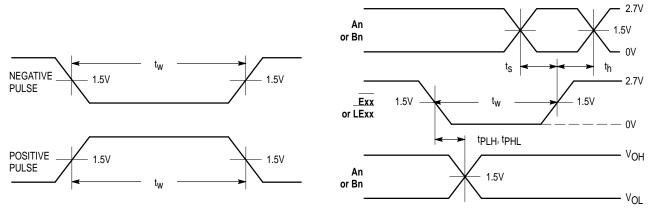


# WAVEFORM 1 – A/B to B/A PROPAGATION DELAYS $t_R = t_F = 2.5 ns$ , 10% to 90%; f = 1MHz; $t_W = 500 ns$



WAVEFORM 2 – OExx/Exx to A or B OUTPUT ENABLE AND DISABLE TIMES  $t_R = t_F = 2.5 ns, \, 10\% \ to \ 90\%; \, f = 1 MHz; \, t_W = 500 ns$ 

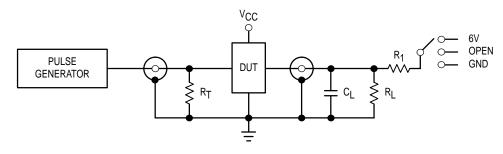
Figure 1. AC Waveforms



WAVEFORM 3 - INPUT PULSE DEFINITION  $t_R = t_F = 2.5$ ns, 10% to 90% of 0V to 2.7V

WAVEFORM 4 - Enable to A or B PROPAGATION DELAYS, Enable MINIMUM PULSE WIDTH, A or B to Enable SETUP AND HOLD TIMES  $t_R = t_F = 2.5 ns$ , 10% to 90%; f = 1MHz;  $t_W = 500 ns$  except when noted

Figure 2. AC Waveforms (continued)

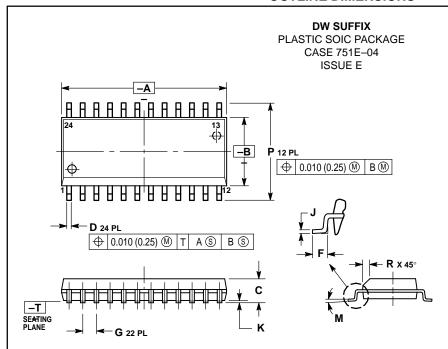


TEST	SWITCH
t <sub>PLH</sub> , t <sub>PHL</sub>	Open
tPZL, tPLZ	6V
Open Collector/Drain tpLH and tpHL	6V
<sup>t</sup> PZH <sup>, t</sup> PHZ	GND

 $C_L$  = 50pF or equivalent (Includes jig and probe capacitance)  $R_L$  =  $R_1$  = 500 $\Omega$  or equivalent  $R_T$  =  $Z_{OUT}$  of pulse generator (typically 50 $\Omega$ )

Figure 3. Test Circuit

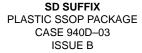
#### **OUTLINE DIMENSIONS**



#### NOTES:

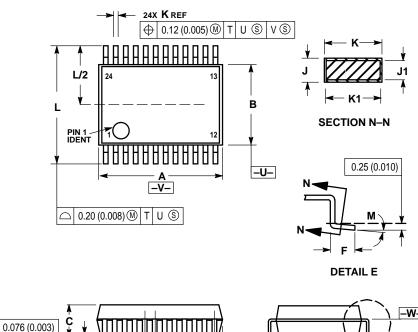
- DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	15.25	15.54	0.601	0.612
В	7.40	7.60	0.292	0.299
С	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.41	0.90	0.016	0.035
G	1.27	BSC	0.050	BSC
J	0.23	0.32	0.009	0.013
K	0.13	0.29	0.005	0.011
M	0°	8°	0°	8°
Р	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029



**DETAIL E** 

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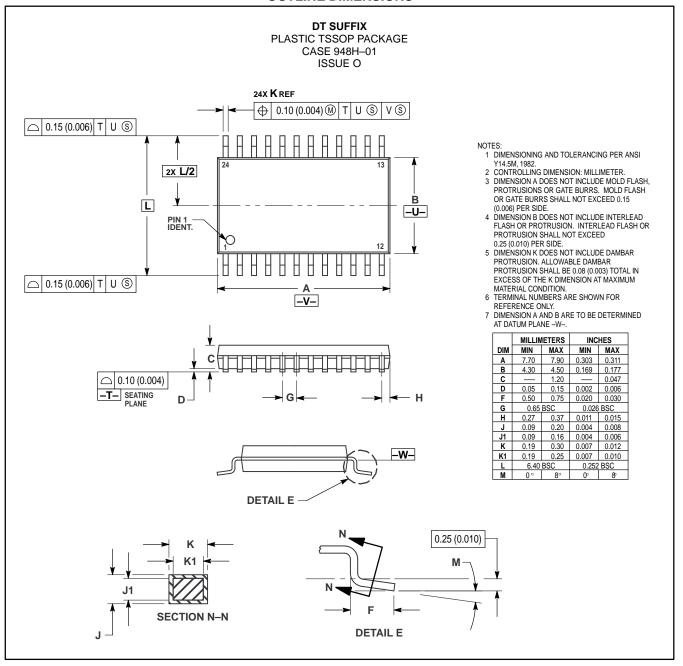
- NOTES:
  4 DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
  5 CONTROLLING DIMENSION: MILLIMETER.
- 6 DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15
- OR GATE BURRS SHALL NOT EXCELS 0.13
  (0.006) PER SIDE.
  7 DIMENSION B DOES NOT INCLUDE INTERLEAD
  FLASH OR PROTRUSION. INTERLEAD FLASH OR
  PROTRUSION SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  8 DIMENSION K DOES NOT INCLUDE DAMBAR
- DIMENSION K DOES NOT INCLUDE DAMBAR
  PROTRUSION/INTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN
  EXCESS OF K DIMENSION AT MAXIMUM
  MATERIAL CONDITION. DAMBAR INTRUSION SHALL NOT REDUCE DIMENSION K BY MORE THAN 0.07 (0.002) AT LEAST MATERIAL CONDITION.
- 9 TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 10 DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE –W–.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.07	8.33	0.317	0.328
В	5.20	5.38	0.205	0.212
С	1.73	1.99	0.068	0.078
D	0.05	0.21	0.002	0.008
F	0.63	0.95	0.024	0.037
G	0.65	BSC	0.026	BSC
Н	0.44	0.60	0.017	0.024
۲	0.09	0.20	0.003	0.008
J1	0.09	0.16	0.003	0.006
K	0.25	0.38	0.010	0.015
K1	0.25	0.33	0.010	0.013
L	7.65	7.90	0.301	0.311
M	0 °	8∘	00	8

-T- SEATING

#### **OUTLINE DIMENSIONS**



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